Take away messages: what is XPS e-spectrometer: how it works HAXPES: probing depth cross sections **AP-XPS** introduction future: AP-HAXPES with membranes

PhotoElectron Spectroscopy (PES)



PES can probe many features of the electronic structure, thus providing information useful for the comprehension e.g. of spin/charge transport, magnetic properties, local structural order, etc...

- Irradiate a solid with monoenergetic UV/X-ray radiation
- Analyze the energies of the emitted electrons

PHOTOELECTRIC EFFECT



H. Hertz, Ann. Physik 31,983 (1887).
 A. Einstein, Ann. Physik 17,132 (1905). 1921 Nobel Prize in Physics.
 K. Siegbahn, Et. Al.,Nova Acta Regiae Soc.Sci., Ser. IV, Vol. 20 (1967). 1981 Nobel Prize in Physics.







Ultrahigh Vacuum

Sample

Irradiated

Area

No. e-→

True success: chemical analysis with laboratory sources



Reference: hanbook of x ray photoemission spectroscopy



Electron energy analysers

Electrostatic energy analyser





Hemispherical or cilindrical

Broad application field with standard and synchrotron sources

Time of flight



Require pulsed sources, special applications: Time resolved experiment Angular resolved photoemission

The king of analysers: electrostatic hemispherical analyser





3 parts: input lenses hemisphers detectors

Detectors: electron multipliers

Channeltrons



Microchannel plate



Both require vacuum better than 10-6 mbar!!!

<u>**HArd X-ray**</u> Photo<u>E</u>lectron <u>Spectroscopy</u> A tool for looking beneath the surface





parentheses: the universal curve



There are different behaviour below 100eV, not universal

The VOLPE Project

VOLume PhotoEmission from solids with Synchrotron Radiation

5th Framework RTD European Project - 3 years (2002-2005)

ELETTRA (Trieste), INFM (Rome and Trieste), ESRF (Grenoble), LURE (Paris), EPFL (Lausanne), Univ. Neuchatel



OBJECTIVES: 20-40 meV Energy resolution

@ 6-10 keV

- 1) High Resolution/High Flux ESRF ID16 beamline 15-100 meV at 8-10 keV
- 2) Dedicated Spectrometer, power supplies and detector

Challenges:

Power supply stability @HV

SY900 Controller CAN SY900 HV channels Low noise 10kV DC source GND VM GP/B Bus PC embedded

FIG. 5. Block diagram of the power supply system.

Low noise detector: CROSS SECTION!!!

Use the Elettra resource:

https://vuo.elettra.eu/services/elements/WebElements.html

Return to periodic table



VOLPE apparatus at the ID16 beamline of the ESRF



P. Torelli et al. RSI 76 023909 (2005)

Estimation of the bulk sensitivity in HAXPES

Bulk sensitivity in PES is typically estimated via measurements of electron effective attenuation length (λ) , the thickness of the overlayer that reduces to 1/e the intensity I^S of a core level emission from the substrate.



Co wedge

Si - 1s photoemission

26 Å

39 Â

52 Å

65 Å

6000

5000

Bulk vs Surface sensitivity

PRL 100, 167402 (2008)

PHYSICAL REVIEW LETTERS

week ending 25 APRIL 2008

Nature of the Band Gap of In₂O₃ Revealed by First-Principles Calculations and X-Ray Spectroscopy

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 ⁶Chemistry Research Laboratory, Mansfield Road, Oxford OX1 3TA, United Kingdom (Received 5 November 2007; published 25 April 2008)

Bulk and surface sensitive x-ray spectroscopic techniques are applied in tandem to show that the valence band edge for In_2O_3 is found significantly closer to the bottom of the conduction band than expected on the basis of the widely quoted bulk band gap of 3.75 eV. First-principles theory shows that the upper valence bands of In_2O_3 exhibit a small dispersion and the conduction band minimum is positioned at Γ . However, direct optical transitions give a minimal dipole intensity until 0.8 eV below the valence band maximum. The results set an upper limit on the fundamental band gap of 2.9 eV.

DOI: 10.1103/PhysRevLett.100.167402

PACS numbers: 78.70.En, 73.20.At, 78.20.Bh

Change in the partial cross section

G. Panaccione, G. Cautero, M. Cautero, A. Fondacaro, M. Grioni, P. Lacovig, G. Monaco, F. Offi, G. Paolicelli, M. Sacchi, N. Stojic, G. Stefani, R. Tommasini and P. Torelli,

"High-energy photoemission in silver: resolving d and sp contributions in valence band spectra",

J. Phys.: Condens. Matter 17 (2005) 2671-2679.



G. Panaccione, F. Offi, M. Sacchi and P. Torelli, Hard X-ray PhotoEmission Spectroscopy of strongly correlated systems,
Comptes Rendus de Physique 9, 524 (2008)

Ambient pressure XPS



Motivation:

-surface structure may differ from what observed in UHV

-Dynamic effect can play a significant role

-Dynimic processes may be studied

-Material with high vapor pressure can be studied

Problems:

1) Electron analyser require UHV

2) Electron escape depth

Analyser for NAP-XPS (a smart solution...)



Several differential pumping stages

Extremely expensive, brute force.....



Input lenses focalize electron in small apertures to help differential pumping

Example 1: chemical reactivity @ surfaces





Ambient-Pressure X-ray Photoelectron Spectroscopy Study of Cobalt Foil Model Catalyst under CO, H₂, and Their Mixtures

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Supporting Information

ABSTRACT: Ambient-pressure X-ray photoelectron spectroscopy (XPS) was used to investigate the reactions of CO, H₂, and their mixtures on Co foils. We found that CO adsorbs molecularly on the clean Co surface and desorbs intact in vacuum with increasing rate until ~90 °C where all CO desorbs in seconds. In equilibrium with 100 mTorr gas, CO dissociates above 120 °C, leaving carbide species on the surface but no oxides, because CO efficiently reduces the oxides at temperatures ~100 °C lower than H₂. Water as impurities or produced by reaction of CO and H₂ efficiently oxidizes Co even at room temperature. Under 97:3 CO/ H₂ mixture and with increasing temperatures, the Co surface



becomes more oxidized and covered by hydroxyl groups until ~150 °C where surface starts to get reduced, accompanied by carbide accumulation indicative of CO dissociation. A similar trend was observed for 9:1 and 1:1 mixtures, but surface reduction begins at higher temperatures.

KEYWORDS: catalysis, Fischer-Tropsch synthesis, cobalt, ambient-pressure X-ray photoelectron spectroscopy

Example 2: solid/liquid interfaces

SCIENTIFIC REPORTS

OPEN Using "Tender" X-ray Ambient Pressure X-Ray Photoelectron Spectroscopy as A Direct Probe of Solid-Liquid Interface

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We report a new method to probe the solid-liquid interface through the use of a thin liquid layer on a solid surface. An ambient pressure XPS (AP-XPS) endstation that is capable of detecting high kinetic energy photoelectrons (7 keV) at a pressure up to 110Torr has been constructed and commissioned. Additionally, we have deployed a "dip & pull" method to create a stable nanometers-thick aqueous electrolyte on platinum working electrode surface. Combining the newly constructed AP-XPS system, "dip & pull" approach, with a "tender" X-ray synchrotron source (2 keV-7 keV), we are able to access the interface between liquid and solid dense phases with photoelectrons and directly probe important phenomena occurring at the narrow solid-liquid interface region in an electrochemical system. Using this approach, we have performed electrochemical oxidation of the Pt electrode at an oxygen evolution reaction (OER) potential. Under this potential, we observe the formation of both Pt²⁺ and Pt⁴⁺ interfacial species on the Pt working electrode *in situ*. We believe this thin-film approach and the use of "tender" AP-XPS highlighted in this study is an innovative new approach to probe this key solid-liquid interface region of electrochemistry.

Example 3: the new solution: membranes!

Atmospheric pressure X-ray photoelectron spectroscopy apparatus: Bridging the pressure gap

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One of the main goals in catalysis is the characterization of solid/gas interfaces in a reaction environment. The electronic structure and chemical composition of surfaces become heavily influenced by the surrounding environment. However, the lack of surface sensitive techniques that are able to monitor these modifications under high pressure conditions hinders the understanding of such processes. This limitation is known throughout the community as the "pressure gap." We have developed a novel experimental setup that provides chemical information on a molecular level under atmospheric pressure and in presence of reactive gases and at elevated temperatures. This approach is based on separating the vacuum environment from the high-pressure environment by a silicon nitride grid—that contains an array of micrometer-sized holes—coated with a bilayer of graphene. Using this configuration, we have investigated the local electronic structure of catalysts by means of photoelectron spectroscopy and in presence of gases at 1 atm. The reaction products were monitored online by mass spectrometry and gas chromatography. The successful operation of this setup was demonstrated with three different examples: the oxidation/reduction reaction of iridium (noble metal) and copper (transition metal) nanoparticles and with the hydrogenation of propyne on Pd black catalyst (powder). *Published by AIP Publishing*. [http://dx.doi.org/10.1063/1.4951724]

Take away messages: XPS basic principles e-spectrometer: how it works HAXPES: incresed probing depth change in relative (s,p,d) cross sections **AP-XPS** introduction future: AP-HAXPFS with membranes